



Product Description

The D10040200PH1 is a Hybrid Power Doubler amplifier module. The part employs GaAs pHEMT and GaN HEMT die and is operated from 45MHz to 1000MHz. It provides excellent linearity and superior return loss performance with low noise and optimal reliability.

Features

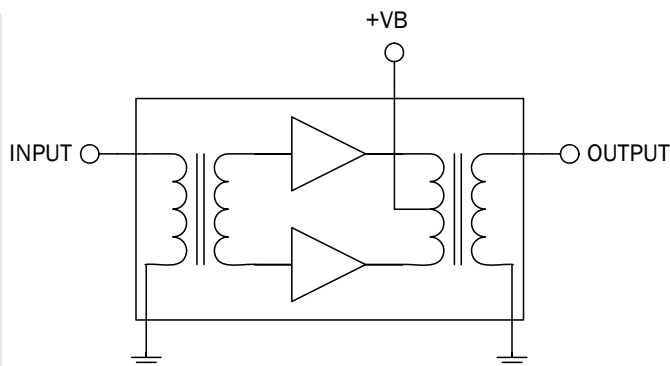
- Extremely High Output Capability
- Excellent Linearity
- Superior Return Loss Performance
- Extremely Low Distortion
- Optimal Reliability
- Low Noise
- Unconditionally Stable Under All Terminations
- 20.0dB Min. Gain at 1GHz
- 450mA Max. at 24VDC

Applications

- 45 MHz to 1000 MHz CATV Amplifier Systems

Optimum Technology Matching® Applied

- GaAs HBT
- GaAs MESFET
- InGaP HBT
- SiGe BiCMOS
- Si BiCMOS
- SiGe HBT
- GaAs pHEMT
- Si CMOS
- Si BJT
- GaN HEMT
- RF MEMS



Parameter	Specification			Unit	Condition
	Min.	Typ.	Max.		
Overall					$V_B = 24V; T_{MB} = 30^\circ C; Z_S = Z_L = 75\Omega$
Power Gain	18.5	19.0	19.5	dB	f = 45 MHz
	20.0	20.5	21.5	dB	f = 1000 MHz
Slope [1]	1.0	1.5	2.5	dB	f = 45 MHz to 1000 MHz
Flatness of Frequency Response			0.8	dB	f = 45 MHz to 1000 MHz (Peak to Valley)
Input Return Loss	20.0			dB	f = 45 MHz to 160 MHz
	18.0			dB	f = 160 MHz to 870 MHz
	14.0			dB	f = 870 MHz to 1000 MHz
Output Return Loss	20.0			dB	f = 45 MHz to 160 MHz
	18.0			dB	f = 160 MHz to 870 MHz
	14.0			dB	f = 870 MHz to 1000 MHz
Noise Figure		3.0	4.0	dB	f = 50 MHz to 1000 MHz
Total Current Consumption (DC)		430.0	450.0	mA	

1. The slope is defined as the difference between the gain at the start frequency and the gain at the stop frequency.

Absolute Maximum Ratings

Parameter	Rating	Unit
RF Input Voltage (single tone)	65	dBmV
DC Supply Over-Voltage (5 minutes)	30	V
Storage Temperature	-40 to +100	°C
Operating Mounting Base Temperature	-30 to +100	°C



Caution! ESD sensitive device.

Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical performance or functional operation of the device under Absolute Maximum Rating conditions is not implied.

RoHS status based on EU Directive 2002/95/EC (at time of this document revision).

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Parameter	Specification			Unit	Condition
	Min.	Typ.	Max.		
Distortion data 40 MHz to 550 MHz					
CTB		-77	-74	dBc	79 ch 7 dB tilted; $V_0=50$ dBmV at 550 MHz, plus 75 digital channels (-6 dB offset) ^[2]
XMOD		-71	-68	dBc	79 ch 7 dB tilted; $V_0=50$ dBmV at 550 MHz, plus 75 digital channels (-6 dB offset) ^[2]
CSO		-71	-68	dBc	79 ch 7 dB tilted; $V_0=50$ dBmV at 550 MHz, plus 75 digital channels (-6 dB offset) ^[2]
CIN	65	68		dB	79 ch 7 dB tilted; $V_0=50$ dBmV at 550 MHz, plus 75 digital channels (-6 dB offset) ^[2]

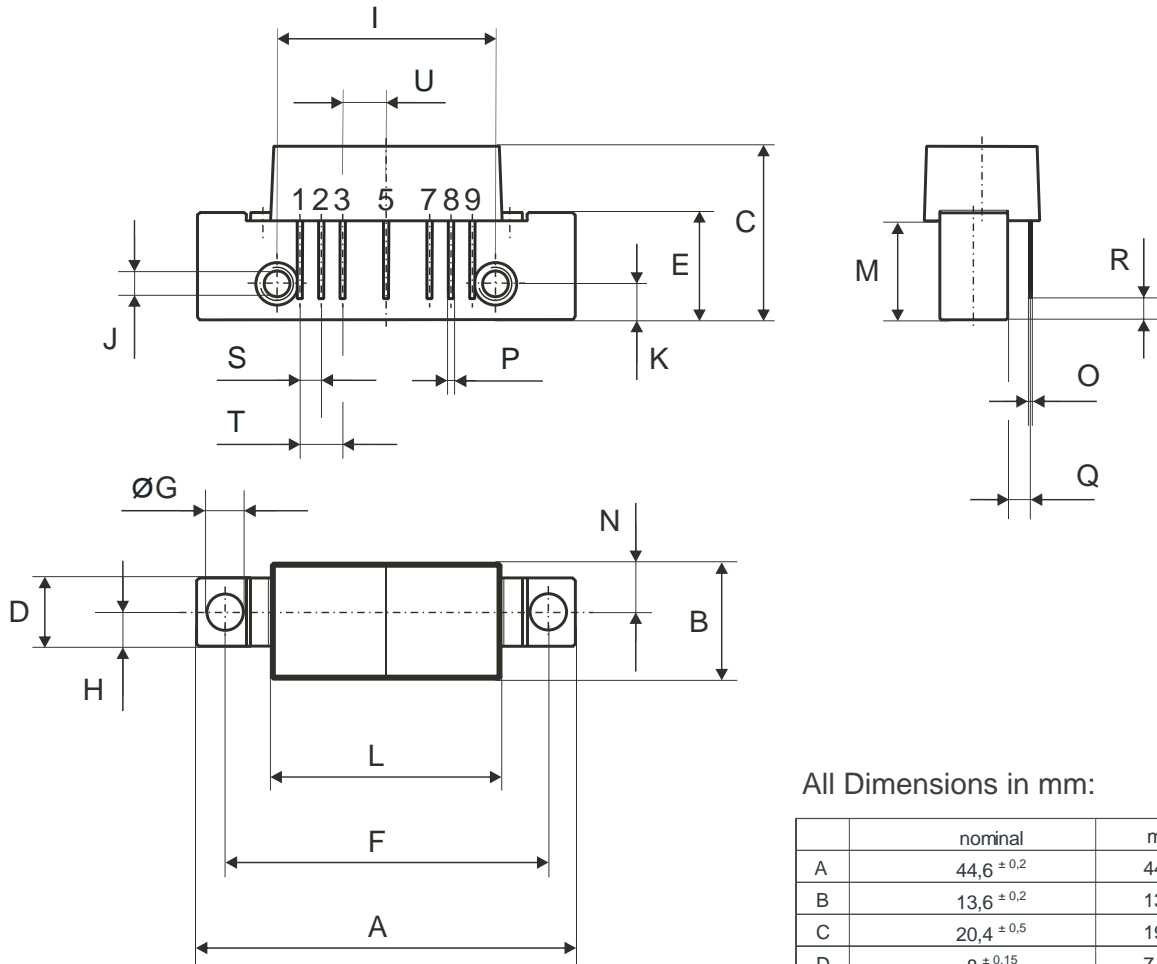
2. 79 analog channels, NTSC frequency raster: 55.25 MHz to 547.25 MHz, +43 dBmV to +50 dBmV tilted output level, plus 75 digital channels, -6 dB offset relative to the equivalent analog carrier.

Composite Second Order (CSO) - The CSO parameter (both sum and difference products) is defined by the NCTA.

Composite Triple Beat (CTB) - The CTB parameter is defined by the NCTA.

Cross Modulation (XMOD) - Cross modulation (XMOD) is measured at baseband (selective voltmeter method), referenced to 100% modulation of the carrier being tested.

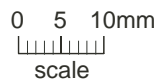
Carrier to Intermodulation Noise (CIN) - The CIN parameter is defined by ANSI/SCTE 17 (Test Procedure for Carrier to Noise)



All Dimensions in mm:

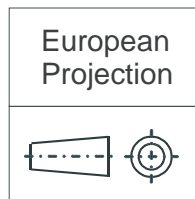
	nominal	min	max
A	44,6 ±0,2	44,4	44,8
B	13,6 ±0,2	13,4	13,8
C	20,4 ±0,5	19,9	20,9
D	8 ±0,15	7,85	8,15
E	12,6 ±0,15	12,45	12,75
F	38,1 ±0,2	37,9	38,3
G	4 ^{+0,2 / -0,05}	3,95	4,2
H	4 ±0,2	3,8	4,2
I	25,4 ±0,2	25,2	25,6
J	UNC 6-32	-	-
K	4,2 ±0,2	4,0	4,4
L	27,2 ±0,2	27,0	27,4
M	11,6 ±0,5	11,1	12,1
N	5,8 ±0,4	5,4	6,2
O	0,25 ±0,02	0,23	0,27
P	0,45 ±0,03	0,42	0,48
Q	2,54 ±0,3	2,24	2,84
R	2,54 ±0,5	2,04	3,04
S	2,54 ±0,25	2,29	2,79
T	5,08 ±0,25	4,83	5,33
U	5,08 ±0,25	4,83	5,33

Pinning:



	1	2	3	4	5	6	7	8	9
INPUT									
GND									
GND									
+VB									
GND									
GND									
OUTPUT									

Notes:



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